


Edge channels in a graphene Fabry-Pérot interferometer

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Quantum-mechanical calculations of electron magnetotransport in graphene Fabry-Pérot interferometers are presented with a focus on the role of spatial structure of edge channels. For an interferometer that is made by removing carbon atoms, which is typically realized in nanolithography experiments, the constrictions are shown to cause strong interchannel scattering that establishes local equilibrium and makes the electron transport nonadiabatic. Nevertheless, two-terminal conductance reveals a common Aharonov-Bohm oscillation pattern, independent of crystallographic orientation, which is accompanied by single-particle states that sweep through the Fermi energy for the edge channels circulating along the physical boundary of the device. The interferometer constrictions host the localized states that might shorten the device or disrupt the oscillation pattern. For an interferometer that is created by electrostatic confinement, which is typically done in the split-gate experiments, electron transport is shown to be adiabatic with Aharonov-Bohm interference observable only at some ranges of magnetic field, with interfering path going through depletion regions. Interference visibility decays exponentially with temperature with a weaker dependence at low temperature.

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I. INTRODUCTION

Quantum Hall interferometers that operate on the Aharonov-Bohm effect have recently been demonstrated in graphene, with high visibility and no Coulomb charging effects [1,2]. This suggests graphene-based interferometers as a better platform for studying the exchange statistics of anionic quasiparticles [3] in comparison to the traditional GaAs-based counterpart [4,5]. The conductance oscillations that were measured in Refs. [1,2] were well described by a theoretical model that is based on an assumption of idealized one-dimensional channels circulating along the edges of the device in the quantum Hall effect (QHE) regime [5–8]. While good agreement between experiments and the theory seemingly validates the chosen model, or at least does not disprove it, the lack of the spatial structure of the edge states and disregard for electron scattering at the constriction regions in the phenomenological modeling leaves an open question about the physical mechanisms behind the electron interference in the studied devices. The problem is evidenced by strong electron scattering that occurs at the graphene interfaces (i.e., the regions where either device size or crystallographic orientation changes) that has been observed in graphene nanoribbons [9], constrictions [10–12], and other structures [13,14]. As was already pointed out in Ref. [1], “quantum Hall inter-

ferometer experiments require a precise knowledge of the edge-channel configuration.” Therefore, getting this knowledge, particularly due to massless Dirac fermions in the QHE regime, is necessary for both the interpretation of the interferometry experiments and for the foundation of theories such as those in Refs. [1,2] and Refs. [5–7].

Previous studies of mesoscopic graphene devices operating in the QHE regime have addressed energy structure, electronic states and transport in nanoribbons [10,15–18], p-n heterojunctions [19,20], rings [21], and others [13,22,23]. These studies have evidenced the existence of edge states [8], which flow in only one direction along the physical edge of the sample. Edge states flowing in an opposite direction exist at the opposite edge, and it is the absence of scattering between these two edges that constitutes the fundamental reason for the robustness of the quantization of QHE [24]. In graphene, the relativistic nature of charge carriers manifests in the so-called anomalous QHE with Landau level (LL) present at zero energy, which separates states with hole character from states with electron character [25,26]. The edge states with the same index of propagating mode, following the standard terminology [27], are referred to in this study as an edge channel.

This paper will provide a microscopic theory of edge channel transport in a graphene interferometer operating on the Aharonov-Bohm effect and will also elucidate the role of the spatial structure of the edge states in electron quantum interference. To this end, the tight-binding model of graphene placed in a perpendicular magnetic field is employed for numerical quantum transport calculations. The interferometer’s geometry is created from an infinite graphene nanoribbon, either by removing carbon atoms or by electrostatic confinement in such a way that a square central region is formed between two narrow constrictions, similarly to the

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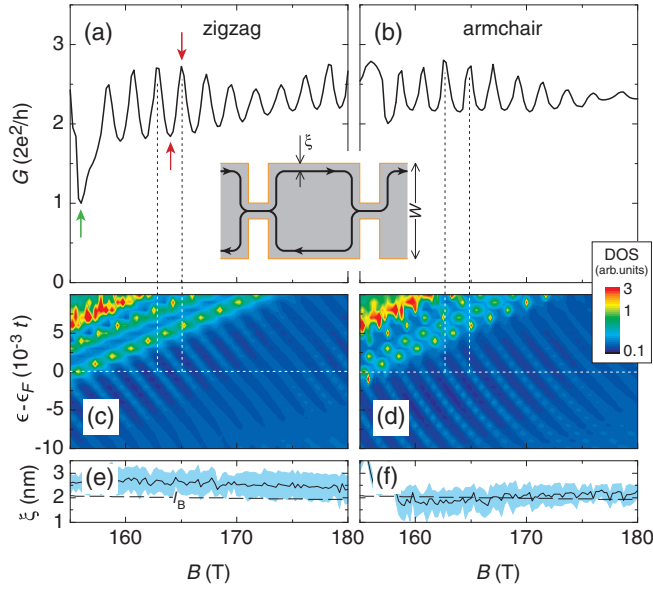


FIG. 1. Conductance G , single-particle state spectroscopy and edge channel displacement ξ in graphene interferometers with zigzag (left-hand panels) and armchair (right-hand panels) orientation. [(a) and (b)] G oscillates as a function of magnetic field B with peaks matching the crossings of the resonant energy levels and the Fermi energy ϵ_F in (c) and (d). The energy levels can be traced by enhanced DOS in (c) and (d), which is obtained by integrating local DOS over the central region of interferometer (a dot in between of two constrictions). Another set of the energy levels, with the positive slope, is due to the states localized at the constrictions. The geometrical area of the dot, reduced by ξ , whose evolution is plotted in (e) and (f), defines an interfering area that is enclosed by the clockwise propagating edge channel as illustrated in the inset between (a) and (b). The dot geometry is a square with sides $W = 50$ nm. The arrows in (a) mark B for which the edge states are shown in Figs. 2 and 3. The dashed line in (e) and (f) is the magnetic length l_B ; blue area denotes the standard deviation.

Fabry-Pérot device [1,2]; see the inset in Figs. 1(a) and 1(b). These two types of lateral confinement correspond to a fabrication technique based on nanolithography [12,16,28] and split-gates [1,2]. For both cases, quantum transport calculations reveal a common Aharonov-Bohm (AB) interference pattern [1,2,4–6,20,24,27,29] in conductance, which is due to edge channels circulating along device physical boundaries and scattered at the constrictions. Every conductance peak corresponds to the single-particle state sweeping through the Fermi energy. Conductance oscillations are independent of the crystallographic orientation of the graphene lattice. In contrast to traditional GaAs-based devices, where electron transport in the QHE regime is adiabatic [4–8,24,27,29], AB interference in graphene interferometers that is made by removing carbon atoms occurs because the edge states propagate nonadiabatically and equilibrate locally at the constrictions (interface regions). Relatively strong confinement for Fermi electron gas in graphene is found to cause electron localization along the constriction and might cause a short circuit or deviation in the AB interference signal. In the case of electrostatic confinement, for a device of the same geometry, transport is adiabatic, somewhat similarly to that found in traditional GaAs-based

interferometers [4,5,7,29], though the Klein tunneling [26] affects edge channel propagation and AB interference is observable only for some ranges in magnetic field. Interference visibility decays overall exponentially with T , with weaker dependence at low T , in agreement with recent experiments [1,20].

This paper is organized as follows. The theoretical model is formulated in Sec. II. The results are presented together with their interpretation and implications for experiment in Sec. III. The main conclusions are summarized in Sec. IV.

II. MODEL

The model is based on the standard nearest-neighbor tight-binding Hamiltonian on a honeycomb lattice,

$$H = \sum_i \epsilon_i a_i^\dagger a_i - \sum_{\langle i,j \rangle} t_{ij} (a_i^\dagger a_j + \text{H.c.}), \quad (1)$$

where ϵ_i is the on-site energy, a_i^\dagger (a_i) is the creation (destruction) operator of the electron on the site i , and the angle brackets denote the nearest-neighbor indices. The magnetic field, B , is included via Peierls substitution,

$$t_{ij} = t \exp \left(i \frac{2\pi}{\Phi_0} \int_{\mathbf{r}_i}^{\mathbf{r}_j} \mathbf{A} \cdot d\mathbf{r} \right), \quad (2)$$

where $\mathbf{A} = B(-y, 0, 0)$ is the vector potential in the Landau gauge, \mathbf{r}_i is the coordinate of the site i , $\Phi_0 = h/|e|$ is the flux quantum, $t = 2.7$ eV. Hamiltonian (1) with $\epsilon_i = 0$ is known to describe the π -band dispersion of graphene well at low energies [30] and has been used in numerous studies of electron transport in graphene nanostructures [13,14,17,21,26,31].

Effects due to next-nearest-neighbor hopping, spin, and electron-electron interactions are outside of the scope of this study.

The Green's function of the system connected at its two ends to the semi-infinite leads is written as [24]

$$\mathcal{G}(\epsilon) = [I\epsilon - H - \Sigma_L(\epsilon) - \Sigma_R(\epsilon)]^{-1}. \quad (3)$$

Here H describes the scattering region that includes the interferometer itself and a part of the leads, I is the unitary operator, $\Sigma_L(\epsilon)$ is the self-energy due to the semi-infinite left lead at electron energy ϵ , and $\Sigma_R(\epsilon)$ is similarly for the right lead. The lead self-energies are obtained from the surface Green's functions by the method given in Ref. [32]. The system is supposed to be whole graphene made, including the leads.

Having $\mathcal{G}(\epsilon)$ calculated allows one to obtain observable quantities, like density of states (DOS) and conductance [24]. The local density of states (local DOS) for the i th site is given by the diagonal elements of the Green's function as

$$\rho_i(\epsilon) = -\frac{1}{\pi} \text{Im}[\mathcal{G}_{ii}(\epsilon)]. \quad (4)$$

The two-terminal (Hall) conductance G of the system is obtained from Landauer-Büttiker formula, which relates conductance to the scattering properties of the system [33]

$$G = \frac{2e^2}{h} \sum_{\beta\alpha} t_{\beta\alpha} = \frac{2e^2}{h} \sum_{\beta\alpha} \frac{v_\beta}{v_\alpha} |s_{\beta\alpha}|^2, \quad (5)$$

where $t_{\beta\alpha}$ is the transmission coefficient from incoming state α in the left lead to outgoing state β in the right lead, $s_{\beta\alpha}$ is the corresponding scattering amplitude, v_α and v_β are the group velocities for those states, all at the Fermi energy ϵ_F . $s_{\beta\alpha}$ is obtained from the Green's function that connects the first and last slices of the scattering region, see Appendix B. Another quantity of interest is the probability of electron density $|\Psi_\alpha|^2$ (the wave functions modulus), which is obtained from the wave functions in the leads, $s_{\beta\alpha}$, and the Green's function (3) by applying Dyson equation recursively as described in Appendix B.

III. RESULTS

The system studied is a graphene interferometer that is made from a nanoribbon in an armchair or zigzag configuration by trimming (etching) carbon atoms away or by applying electrostatic potential, see the inset in Fig. 1. Two (identical) constrictions define the central region similarly to an open quantum dot. For simplicity, the results are presented for rectangular-shaped constrictions; a smooth constriction will be commented on. Adopting zigzag and armchair terminology from underlying nanoribbon structure, the interferometer is below referred to as either a zigzag or armchair. The operation regime is chosen to support three channels for electron propagation within which electron can interfere. For a 50-nm-wide ribbon, which serves as an electron reservoir for the channels, this is achieved at $\epsilon_F = 0.2 t$ and $B = 155\text{--}180$ T [34]. Appendix A elaborates on the propagating states in the chosen regime. The temperature is $T = 0$ K unless otherwise stated.

A. Edge channel interference

Numerical calculation of quantum electron transport, described by Eqs. (1)–(5), reveals conventional AB conductance oscillations [4,5,24,27,29] in a graphene interferometer, irrespective of crystallographic orientation; see Figs. 1(a) and 1(b). The peaks in G correspond to the resonant states passing through ϵ_F , similarly to what was found in Refs. [5,29]. These resonant states can be traced in Figs. 1(c) and 1(d) as bright trenches with a negative slope (lines of constant phase). Sloping downward with increasing B implies that degeneracy of the occupied LLs increases via their edge states, provided by the geometry confinement that makes LLs to rise in energy on approaching the sample boundary [24,27]. Downward sloping corroborates AB regime of interference, as opposed to Coulomb dominated regime [4,7]. For each LL, the degree of degeneracy is quantified by the number of states per unit area, which increases as B/Φ_0 . Every resonant state is a result of the constructive interference of the electron wave in the edge channels that are backscattered at the two constrictions. The difference between phases in two arms of the interferometer is proportional to the total flux Φ enclosed by the area S of the interfering path [24]; $\Phi = BS$. Changing Φ by Φ_0 , via applied B , causes the phase difference to accumulate a value of 2π and G to develop one oscillation period [5,24]. One period, $\Delta B = 2.22$ and 2.16 T for zigzag and armchair configuration, yields area, $S = 1872$ and 1924 nm², that is less than the geometrical area of the central region 2500 nm². This discrepancy might be attributed to a finite spatial extent

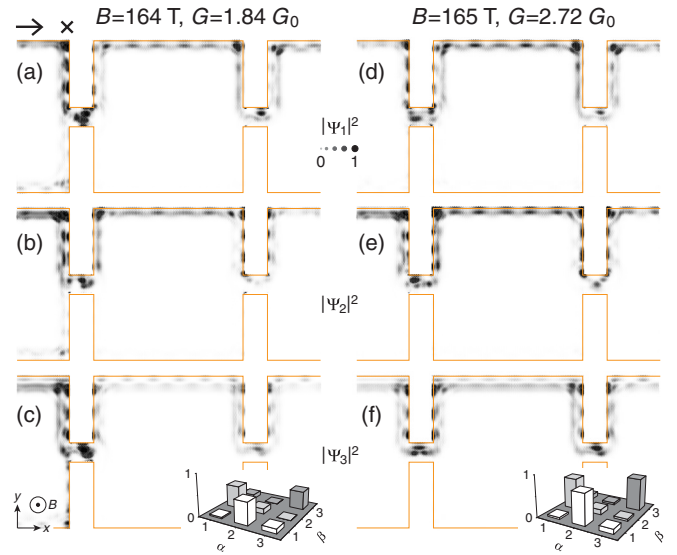


FIG. 2. The wave function modulus $|\Psi_\alpha|^2$ of α th incoming state for B marked by the red arrows in Fig. 1(a). The left-hand (right-hand) panels represent the minima (maxima) of G oscillation. In (a), the arrow and cross illustrate schematically the incoming state and forward scattering to another states that occurs at the constriction bend. The insets in (c) and (f) show the transmission coefficients from incoming α to outgoing β state. $G_0 = 2e^2/h$.

of the edge channel, so the interfering area is smaller than the geometrical one. Figures 1(e) and 1(f) substantiate this argument by showing an averaged edge channel distance from the physical boundary $\xi = [\langle \mathbf{r} | \psi_\alpha \rangle]_{\alpha,x}$, where averaging is done over channels and the straight segments along the boundaries. ξ is about the magnetic length l_B and, interestingly, does not reveal any clear beat of ΔB as it was argued to occur in the Coulomb dominated regime [7]. Slightly larger ξ for zigzag orientation, in comparison to armchair one, explains slightly smaller S and larger ΔB . Thus, G oscillations in graphene AB interferometer are due to interference of the edge channels propagating at about l_B distance from the device boundaries.

Because zigzag and armchair interferometers reveal qualitatively similar dependencies for G and the structure of energy levels, Fig. 1, below only zigzag configuration is considered.

Figure 2 shows the edge states characterizing conductance oscillation at its peak and dip values. The details on the electronic states entering and leaving the interferometer, which are at the openings in these plots, are given in the Appendix A. Edge channel visualization leads to immediate conclusion: A distinct feature of electron transport in a graphene interferometer in comparison to a conventional GaAs-based interferometer [4,5,7,29] is *nonadiabaticity due to strong scattering between the edge states that occurs at the constrictions*. Even though G varies by nearly one conductance quanta over B interval in Figs. 1(a) and 1(b), the oscillations are not caused by the highest occupied LL edge state (as it does for a conventional GaAs-based interferometer) but rather by a mix of all of the states. Strong interchannel scattering is further evidenced by the transmission coefficients in the insets in Figs. 2(c) and 2(f). This indicates local equilibrium [27] of the edge states due to graphene interfaces. The effect develops clearly at the constriction bending as illustrated by the arrow and in

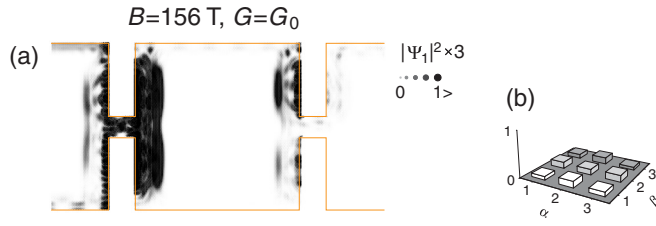


FIG. 3. Short circuit of the interferometer by the localized states at the constrictions. (a) The first propagating state $\alpha = 1$ with $|\Psi_1|^2$ magnified and truncated (for the sake of better visualization). Similarly strong (exponential) localization at the constriction occurs for all other propagating states; the transmission coefficients are shown in (b). $B = 156$ T is marked by the green arrow in Fig. 1(a).

Fig. 2(a). It is essentially the same for all bends along the edge channel path. If rectangular shaped constriction is smoothed out toward a cosinelike profile, then the results do not change qualitatively thus implying that nonadiabaticity is a result of abrupt lattice termination.

Another observation in Fig. 2 is valley selective scattering ($t_{2\leftarrow 1} > t_{3\leftarrow 1}$) in the graphene interferometer, which is in line with conclusion about valley degeneracy lifting of AB interference in graphene rings [21].

The interferometer constrictions, acting as scattering centers for incident electrons, host another set of the single-particle states that rather depopulate in increasing B —visible as bright trenches with a positive slope in Figs. 1(c) and 1(d). These states are localized along the constrictions and cause shorting in case of the zigzag interferometer due to their coupling to and backscattering the incident states in the edge channels at the entrance constriction: G drops to $2e^2/h$ at $B = 156$ T in Fig. 1(a), see Fig. 3. For the armchair interferometer, AB oscillation periodicity is seemingly violated at B , for which the localized states cross ϵ_F . The difference between armchair and zigzag interferometers might be attributed to the different atomic arrangements of the edges and consequently to different low-energy electronic states causing localization [35]. Note that the armchair interferometer in the present study is crystallographically an inverse of a zigzag one in the sense that all of the zigzag edges are replaced by armchair edges and vice versa. It is known that depending on the coupling details between the electronic states transmission through a mesoscopic system can reveal resonances or antiresonances [36]. The existence of the localized states at the constrictions and the shorting in case of the zigzag interferometer, Fig. 3, imply that the strong electron backscattering on the graphene interfaces, which has been previously observed for different structures at zero B [9,13,14], also persists in the QHE regime.

B. Electrostatic confinement

The Fabry-Pérot interferometers that were studied experimentally in Refs. [1,2] were made from a uniform graphene layer rather by imposing electrostatic confinement. In those studies, the fabricated devices contained additional split gate electrodes that expelled the charge carriers from the area beneath by shifting ϵ_F into the energy gap between LLs. The gap formation was controlled in separate measurements to

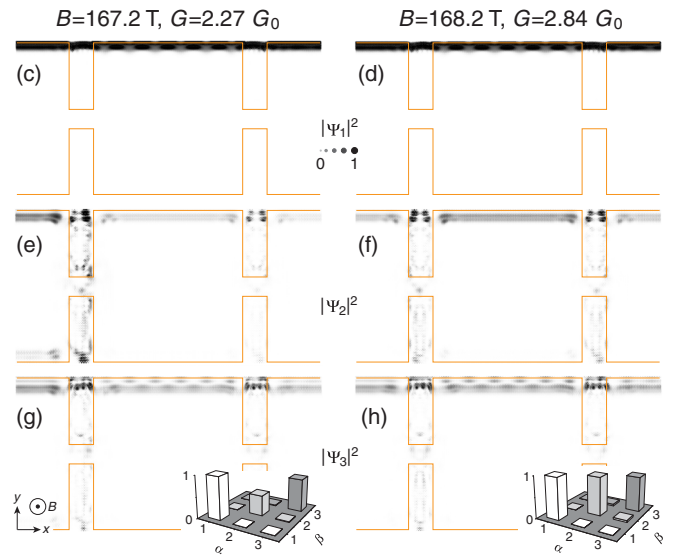
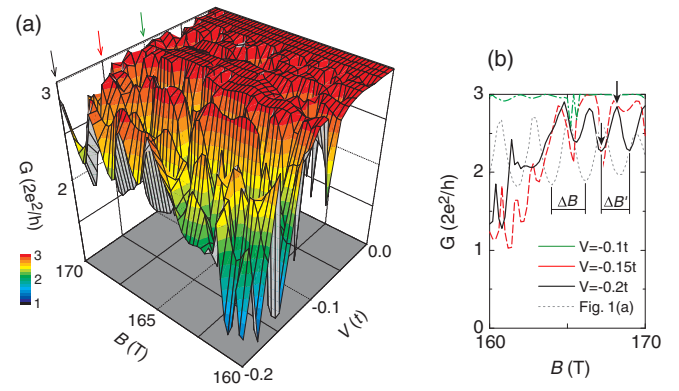


FIG. 4. (a) Conductance map $G(B, V)$ for a zigzag interferometer with electrostatically defined constrictions. G is additionally color coded. The arrows mark potentials V selected for the plot (b). V varies over the depletion areas whose geometry is exactly the same as the areas with removed carbon atoms in the interferometer studied in Fig. 1. Conductance from the latter is shown by the dotted line in (b) for reference. $V = 0$ corresponds to no confinement; $V = -\epsilon_F = -0.2 t$ is for the graphene charge neutrality in the depletion regions. ΔB marks the AB period. [(c)–(h)] Same as Fig. 2 but for $V = -0.2 t$. Corresponding B are marked by the arrows in (b).

occur at the graphene charge neutrality point in the magnetic field, arguably due to electron interactions. The structures that are studied theoretically in the previous subsection are made by removing (etching) carbon atoms away, as it is routinely done in other experiments that based on nanolithography [12,16,28]. The latter seemingly produces the strongest version of confinement, which raises the question about the interference pattern when confinement weakens. To keep the analysis simple, the same geometries as above are taken but with an electrostatic potential applied to form the constrictions, $V = \epsilon_i$, where the site i belongs to the depletion (split gated [1,2]) regions, and Hamiltonian (1) is modified appropriately.

Figure 4 shows conductance in the zigzag interferometer as a function of B and V . Several features of electrostatic confinement can be observed. The first feature is that AB oscillations are seen in certain ranges of the magnetic field, such

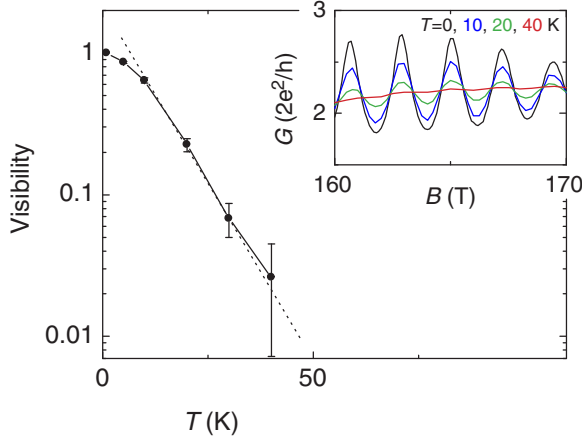


FIG. 5. Temperature dependence of the normalized visibility for zigzag interferometer. The error bars correspond to the standard deviation. The straight dotted line shows the exponential dependence and is a guide for eye. The inset shows smearing G oscillations for several T .

as $B = 163\text{--}170$ T for $V = -0.2t$; as detailed in Fig. 4(b). For $V = -0.2t$, the region under the top gates brings the graphene electron system to the charge neutrality and a QHE condition in which the highly degenerate zeroth LL [15,18,25,26] is at ϵ_F . In contrast to the regime that was utilized in Refs. [1,2], where a gap in the energy spectrum occurs, the noninteracting model here operates with (valley and spin) degenerated LL at the charge neutrality point. Therefore, from bare existence of AB interference in G , one may conclude that electrostatic confinement is sufficient to define AB interferometer even without the gap. The second feature in Fig. 4(b) is the smaller oscillation period for the interferometer with electrostatic confinement $\Delta B' < \Delta B$, which is due to penetration of the electron wave function into potential barriers of the constrictions, Figs. 4(c)–4(h). For period $\Delta B'$, estimation of the interfering area gives $S' = 2660$ nm², which is slightly larger than the geometric area of the central region. Note how the first edge channels goes straight through electrostatic constrictions due to Klein tunneling. The third feature is multiple aperiodic resonances in G , which reflects resonant tunneling through potential barrier and quantum interference effects that include areas inside the potential barriers. As it is typical for mesoscopic devices, resonances are very sensible to the details of potential barriers and the values of B [37]. Fourth, the transport is *adiabatic* with no interchannel scattering, see the transmission coefficients in the insets in Figs. 3(g) and 3(h).

C. Visibility

Figure 5 shows temperature dependence of the interference visibility, normalized by $\nu(T = 0)$,

$$\nu = \frac{G_{\max} - G_{\min}}{G_{\max} + G_{\min}}, \quad (6)$$

where the effect of T is introduced via the derivative over the Fermi-Dirac function [24],

$$G = -\frac{2e^2}{h} \int d\epsilon \frac{\partial f}{\partial \epsilon} G(\epsilon). \quad (7)$$

As T increases, more neighbor resonance states, Figs. 1(c) and 1(d), contribute to conduction that averages out oscillating amplitude, see inset to Fig. 5. ν decays exponentially over two decades, while there is a visible saturation at low T , in agreement with recent experimental findings [1,20].

IV. CONCLUSION

A quantum-mechanical model of electron magnetotransport in a graphene Fabry-Pérot interferometer, that explicitly accounts for the spatial structure of electron states and their interference and does not rely on any phenomenological parameters (like transmission amplitudes of the constrictions [1,2,5–7]), is presented. For interferometers of different crystallographic orientations, numerical calculations reveal a common Aharonov-Bohm interference effect, irrespective of the orientation of the graphene lattice. Two-terminal conductance oscillates as one magnetic flux quanta is added to the interfering path, accompanied by one single-particle state added to edge channels circulating along the physical boundary of the device. In the case of geometry made by etching, the interferometer constrictions cause strong inter-edge-channel scattering that causes the system to establish a local equilibrium and electron transport to be nonadiabatic. The interferometer constrictions host the localized states that might shorten the device or disrupt the oscillation pattern. Transport, however, is adiabatic in the case of electrostatic confinement, similarly to traditional GaAs-based interferometers [4,5,7,29], though the Klein tunneling affects edge channel propagation and AB interference is observable only for some ranges in magnetic field. Interference visibility decays exponentially with T showing a weaker dependence at low T .

The results suggest that any graphene interface that exposes the physical edges of the graphene lattice acts as an “ideal” contact in the QHE regime. By establishing a local equilibrium, and thus making the edge channels equally populated, a prerequisite is fulfilled for the use of a local resistivity tensor [27]. However, common theories of QHE, where transport is assumed to be adiabatic, are not applicable to such systems or (in particular) to graphene interferometers made by etching nanolithography.

In the experiments in Refs. [1,2], electrostatic confinement was realized by adjusting depletion regions into the energy gap. To account for this, many-electron and (possibly) spin [38] effects should be added to the theory. Also, for a quantitative comparison, the realistic shape (and size) of the split gates and potential due to those split-gates might be needed. The study presented here might serve as a basis the further development of the graphene AB interferometer theories.

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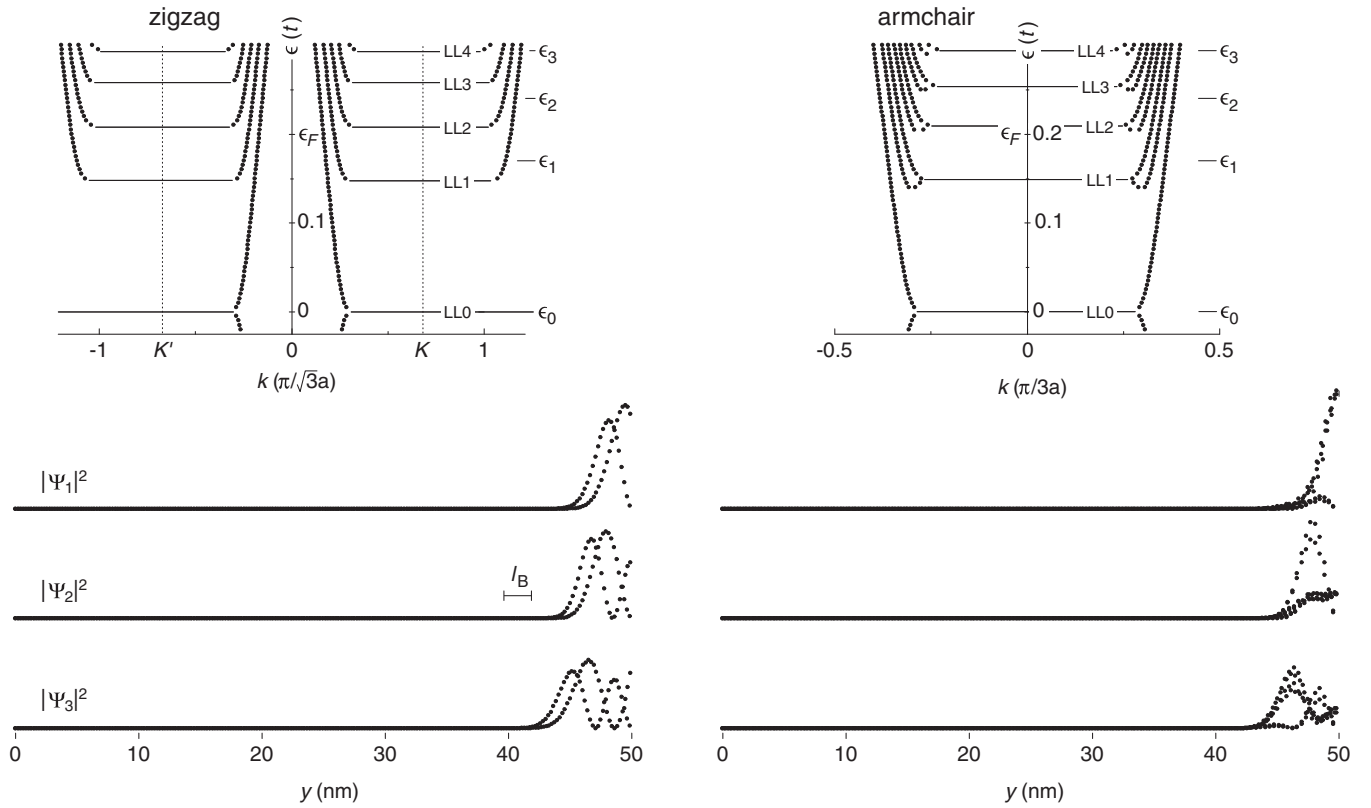


FIG. 6. The band structures (top panels) and wave functions (bottom panels) for zigzag and armchair graphene nanoribbons in the QHE regime, $B = 160$ T. In the top panels, the horizontal solid lines denote LLs and are guides for the eye; the vertical dotted lines denote K and K' points of the first Brillouin zone of graphene. K and K' points coincide at $k = 0$ for the armchair ribbon. ϵ_n labels n th LL in 2D graphene obtained from the Dirac equation. The bottom panels show the wave function modulus $|\Psi_\alpha|^2$ of α th propagating state (projected onto the ribbon cross section) at $\epsilon_F = 0.2t$; ϵ_F is marked on the corresponding top panels. At $B = 160$ T and $l_B = 2.03$ nm. $a = 0.142$ nm.

APPENDIX A: EDGE CHANNELS IN THE LEADS

Figure 6 shows the dispersion relation and wave functions in graphene nanoribbons—the structures which serve as electron reservoirs (leads) in the interferometers studied in the main text. At $B = 160$ T [34], the dispersionless bands can be traced and centered around graphene K and K' points, and be attributed to Landau levels (LLs) [15,18,26]. The identified LLs agree reasonably well with the solution of the Dirac equation in 2D graphene [26]

$$\epsilon_n = v_F \sqrt{2e\hbar Bn}, \quad (\text{A1})$$

where $v_F = 10^6$ m/s and n is the index of electron LL, counted from $n = 0$ at $\epsilon = 0$. At $\epsilon_F = 0.2t$, zeroth and first LLs are occupied in the ribbon bulk and provide, accounting for the valley degeneracy [26], three channels for electron propagation along the ribbon edges (in both directions), see also the left-hand portions of the plots in Figs. 2 and 4(c)–4(h), where the electron states enter the interferometer. In Fig. 6, the wave functions propagating only in one (positive x) direction are shown. (As it is intrinsic to QHE, similar states on the opposite edge propagate in the negative x direction [8,24,27].) The dispersion relations in Fig. 6 reveal electron bands that raise in energy and cross ϵ_F at momentum whose conversion to coordinate space $y = -\hbar k_x / eB$ gives approximate location

of the edge channel [24]. The latter thus can be viewed as real space realisation of the Fermi surface.

Recently, the electron edge states and LL spectroscopy have been directly observed in scanning tunnel microscopy measurements [23]. On approaching the sample boundary, LLs were found to raise in energy and edge channels to be sharply confined within few l_B to the physical boundary of graphene, all consistent with Fig. 6.

APPENDIX B: SCATTERING PROBLEM FOR GRAPHENE INTERFEROMETER

In this Appendix, transmission coefficients, entering the Landauer-Büttiker formula [33] for conductance (5), are derived using the Green's functions. The derivation follows Ref. [32], and the reader is referred to this reference for further details. Similar approaches can be found in Refs. [39–43]. The method is essentially the same as one used for the materials with parabolic band dispersion, where the tight-binding model is formulated on the square lattice [44].

1. Bloch states in ideal GNR

First, let us consider an ideal GNR infinitely long in x direction and consisting of N lattice sites in y direction, Fig. 7. For graphene hexagonal lattice, two orientations are considered as basic, with terminations along ribbon edges

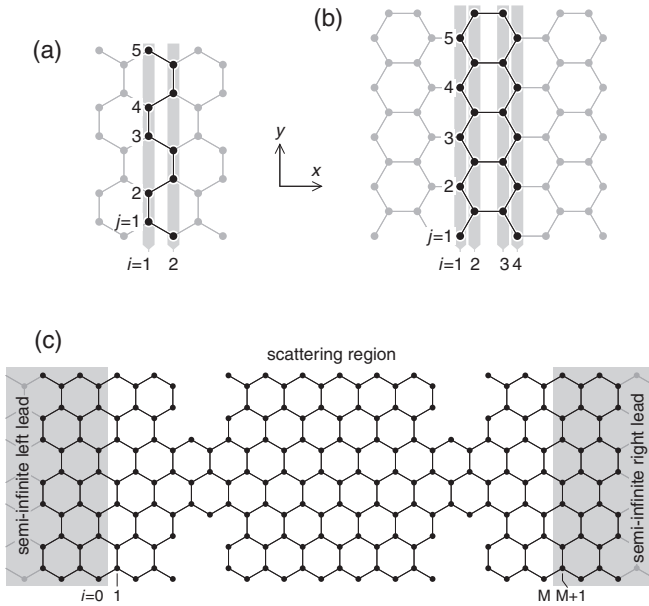


FIG. 7. The unit cells of zigzag (a) and armchair (b) GNRs. The unit cell is periodic in the x direction and is chopped into M transverse slices (denoted by the gray areas) in the y direction. $M = 2$ and $M = 4$ for zigzag and armchair unit cells. In (a) and (b), every slice contains $N = 5$ sites. GNR becomes the semi-infinite leads in the computation domain (c), which also includes the scattering region in between. The scattering region, whose slices run $1 \leq i \leq M$, can generally be of arbitrary geometry [43]. In present study, it has two constrictions, defined either by removing lattice sites as shown in (c) or imposing potential on those sites.

being either zigzag or armchair [26]. The unit cells for these terminations consist of $M = 2$ and 4 slices, Figs. 7(a) and 7(b). Every lattice site corresponds to a carbon atom, more specially, to its p_z orbital [30]. In this approach, no discrimination applies on A and B graphene sublattices [26], and whether the orientation is zigzag or armchair depends solely on connection between the lattice sites.

The solution of the Schrödinger equation with Hamiltonian (1) for the ideal GNR can be written in terms of an ansatz for a Bloch wave,

$$|\psi\rangle = \sum_{\alpha} e^{ik_{\alpha}x} |\chi_{\alpha}\rangle, \quad (\text{B1})$$

where k_{α} is the Bloch wave vector in the direction of translation invariance and $|\chi_{\alpha}\rangle$ is the periodic eigenfunction. The sum in (B1) runs over propagating and evanescent states to form a complete set [45].

For the ideal GNR, the Hamiltonian (1) can be rewritten as a sum of the operators describing the unit cell, the outside region, and coupling between them

$$H = H_{\text{cell}} + H_{\text{out}} + U. \quad (\text{B2})$$

The unit cell term includes the slices $1 \leq i \leq M$, as shown in Figs. 7(a) and 7(b), while the term for the outside region goes all over the other slices, $-\infty < i \leq 0$ and $M + 1 \leq i < \infty$. These two terms are coupled by the transfer integrals (2) acting between slices $0 \leftrightarrow 1$ and $M \leftrightarrow M + 1$. For the Hamiltonian written in the form (B2), the corresponding wave

function is

$$|\psi\rangle = |\psi_{\text{cell}}\rangle + |\psi_{\text{out}}\rangle. \quad (\text{B3})$$

Defining the Green's function in a way suitable for calculations in matrix form [24,39]

$$\mathcal{G} = (E - H + i\eta)^{-1}, \quad (\text{B4})$$

with $\eta \rightarrow 0^+$, the wave function of the cell can be written as

$$|\psi_{\text{cell}}\rangle = \mathcal{G}_{\text{cell}} U |\psi_{\text{out}}\rangle, \quad (\text{B5})$$

where $\mathcal{G}_{\text{cell}}$ is the Green's function of the operator H_{cell} . Taking the matrix elements of the wave functions for the first $i = 1$ and the last $i = M$ slices of the unit cell, this equation can be written in the matrix form

$$\psi_1 = \mathcal{G}_{1,1} U_{1,0} \psi_0 + \mathcal{G}_{1,M} U_{M,M+1} \psi_{M+1}, \quad (\text{B6})$$

$$\psi_M = \mathcal{G}_{M,1} U_{1,0} \psi_0 + \mathcal{G}_{M,M} U_{M,M+1} \psi_{M+1}, \quad (\text{B7})$$

where ψ_i is the vector column describing the wave function for the slice i , $\mathcal{G}_{i,i'}$ is the Green's function matrix connecting slices i and i' , and $U_{i,i'}$ is the matrix of hopping integrals (2). Translation invariance of the unit cell implies $U_{M,M+1} = U_{0,1}$, Figs. 7(a) and 7(b). The Bloch's theorem in terms of the periodic eigenstates,

$$\chi_{i+M} = e^{ikM} \chi_i, \quad (\text{B8})$$

allows further to rewrite Eqs. (B6) and (B7) as the eigenvalue problem,

$$\begin{pmatrix} -\mathcal{G}_{1,M} U_{0,1} & 0 \\ -\mathcal{G}_{M,M} U_{0,1} & I \end{pmatrix}^{-1} \begin{pmatrix} -I & -\mathcal{G}_{1,1} U_{1,0} \\ 0 & -\mathcal{G}_{M,1} U_{1,0} \end{pmatrix} \begin{pmatrix} \chi_1 \\ \chi_0 \end{pmatrix} = e^{ikM} \begin{pmatrix} \chi_1 \\ \chi_0 \end{pmatrix} \quad (\text{B9})$$

where I is the unitary matrix. Equation (B9) has $2N$ eigenvalues and $2N$ eigenvectors, which are the Bloch states classified into N right- and N left-going waves. The right-going solutions consists of traveling waves with velocity in positive x direction and evanescent waves decaying exponentially in the positive x direction. Similarly, the left-going solutions consists of propagating and decaying waves in negative x direction.

If the Bloch wave (B1) is a set of the eigenstates of Hamiltonian (B2), in which H_{out} splits into infinite replicas of H_{cell} connected by U , then the group velocity for an eigenstate α is

$$v_{\alpha} = \frac{1}{\hbar} \frac{\partial}{\partial k} \langle \psi_{\alpha} | H | \psi_{\alpha} \rangle = \frac{iM}{\hbar} \langle \chi_{\alpha} | U e^{ikM} - U^{\dagger} e^{-ikM} | \chi_{\alpha} \rangle, \quad (\text{B10})$$

where U^{\dagger} is the Hermitian conjugate of the coupling operator and $|\psi_{\alpha}\rangle$ is the Bloch wave normalized on unit flux.

2. Surface Green's function

Let us consider a semi-infinite ideal graphene ribbon extending from slice $-m$ to the right, $-m \leq i < \infty$. Suppose that an excitation $|s\rangle$ is applied to its surface slice $i = -m$. Whenever the response $|\psi\rangle$ is related the excitation $|s\rangle$ by a differential operator D_{op} as $D_{\text{op}} |\psi\rangle = |s\rangle$ we can define a Green's function (propagator) and express the response in the form [24]

$$|\psi\rangle = D_{\text{op}}^{-1} |s\rangle = \mathcal{G} |s\rangle, \quad (\text{B11})$$

where $|\psi\rangle$ is the wave function that has to satisfy the Bloch condition (B1). Consider a unit cell of a graphene lattice, $1 \leq i \leq M$, $M = 2$ and 4 for the zigzag and armchair orientation, see Figs. 7(a) and 7(b). Applying the Dyson's equation between the slices 0 and 1 , we obtain

$$\mathcal{G}_{1,-m} = \Gamma_r U_{1,0} \mathcal{G}_{0,-m}, \quad (\text{B12})$$

where $\Gamma_r \equiv \mathcal{G}_{1,1}$ is the right surface Green's function. Evaluating the matrix elements $\langle \psi_1 | \psi \rangle$ of (B11) and making use of (B12), we obtain for each Bloch state α , $\psi_1^\alpha = \Gamma_r U_{1,0} \psi_0^\alpha$. The latter equations can be used for determination of Γ_r

$$\Gamma_r U_{1,0} = \Psi_1 \Psi_0^{-1}, \quad (\text{B13})$$

where Ψ_1 and Ψ_0 are the square matrices composed of the column vectors χ_1^α and χ_0^α , $1 \leq \alpha \leq N$, Eq. (B9), i.e., $\Psi_1 = (\psi_1^1, \dots, \psi_1^N)$, $\Psi_0 = (\psi_0^1, \dots, \psi_0^N)$. The expression for the left surface Green's function Γ_l (i.e., the surface function of the semi-infinite ribbon open to the left) is derived similarly,

$$\Gamma_l U_{1,0}^\dagger = \Psi_M \Psi_{M+1}^{-1}, \quad (\text{B14})$$

where the matrices Ψ_M and Ψ_{M+1} are defined in a similar way as Ψ_1 and Ψ_0 above.

3. Transmission coefficients

To calculate the transmission coefficients and hence evaluate (5), the interferometer structure is divided into three regions: two ideal semi-infinite leads of the width N extending in the regions $i \leq 0$ and $i \geq M+1$, respectively, and the scattering region, Fig. 7(c). The latter composes of two constrictions and the cavity in between, see the inset in Fig. 1(a). In general, the scattering region can contain arbitrary scatterers and be of arbitrary shape [24].

The incoming, transmitted, and reflected states in the leads have the form of Bloch waves (B1),

$$|\psi_\alpha^i\rangle = \sum_{i \leq 0} e^{ik_\alpha^+ x_i} |\chi_\alpha\rangle, \quad (\text{B15})$$

$$|\psi_\alpha^s\rangle = \sum_{i \geq M+1} \sum_{\beta} t_{\beta\alpha} e^{ik_\beta^+ (x_i - x_{M+1})} |\chi_\beta\rangle, \quad (\text{B16})$$

$$|\psi_\alpha^r\rangle = \sum_{i \leq 0} \sum_{\beta} r_{\beta\alpha} e^{-ik_\beta^- x_i} |\chi_\beta\rangle, \quad (\text{B17})$$

where $t_{\beta\alpha}$ ($r_{\beta\alpha}$) are the transmission (reflection) amplitude from the state α to the state β , plus (minus) superscripts for the wave vectors denote right (left) going direction. The sum over β includes outgoing propagating and evanescent states.

The solution of the Schrödinger equation

$$H|\psi\rangle = E|\psi\rangle \quad (\text{B18})$$

with $|\psi\rangle = |\psi_\alpha^s\rangle + |\psi_\alpha^i\rangle$ for the transmitted state in the right lead can be written as

$$|\psi_\alpha^s\rangle = \mathcal{G}(H - E)|\psi_\alpha^i\rangle. \quad (\text{B19})$$

To find the transmission matrix, let us consider the matrix element $\langle \psi_{M+1} | \psi_\alpha^s \rangle$. Using (B19) and applying the Dyson's equation between slices $M+1$ and 0 gives

$$\langle \psi_{M+1} | \psi_\alpha^s \rangle = \mathcal{G}_{M+1,0} U_{0,1} \Psi_1 e^{ik_\alpha^+} - \mathcal{G}_{M+1,1} U_{1,0} \Psi_0. \quad (\text{B20})$$

On the other hand, from (B16)

$$\langle \psi_{M+1} | \psi_\alpha^s \rangle = \Psi_1 \sum_{\beta} s_{\beta\alpha}. \quad (\text{B21})$$

The Dyson's equation further gives $\mathcal{G}_{M+1,0} = -\mathcal{G}_{M+1,1} U_{1,0} \Gamma_l$. As a result, the matrix of transmission amplitudes \mathbf{S} is [32]

$$\Psi_1 \mathbf{S} = -\mathcal{G}_{M+1,0} (U_{0,1} \Psi_1 K_1 - \Gamma_l^{-1} \Psi_0), \quad (\text{B22})$$

where \mathbf{S} has the dimension $N \times N_{\text{prop}}$, N_{prop} is the number of propagating states in the leads, Ψ_0 and Ψ_1 are wave functions at 0 and 1 slices, Γ_l is given by (B14), K_1 is the diagonal matrix with elements $K_{1,\alpha\beta} = e^{ik_\alpha^+} \delta_{\alpha\beta}$. The Green's function $\mathcal{G}_{M+1,0}$ connects $M+1$ and 0 slices, which are the ending slices of the leads attached to the scattering region, Fig. 7(c). To calculate $\mathcal{G}_{M+1,0}$ the standard recursion algorithm is used [32,40,42,43] which is the more efficient method than direct matrix inversion as Eq. (B4) might otherwise suggest [24].

The matrix of the reflection amplitudes \mathbf{R} is derived similarly to (B22) and reads [32]

$$\Psi_0 \mathbf{R} = -\mathcal{G}_{0,0} (U_{0,1} \Psi_1 K_1 - \Gamma_l^{-1} \Psi_0) - \Psi_0. \quad (\text{B23})$$

Together with the transmission amplitudes, the scattering matrix is completely determined and satisfies the unitarity condition implied by current conservation [24].

The sum over transmission and reflection coefficients gives the number of channels open for propagation in the lead, M_{lead} , the so-called sum rule [24]

$$\sum_{\alpha\beta} (|t_{\beta\alpha}|^2 + |r_{\beta\alpha}|^2) = M_{\text{lead}}. \quad (\text{B24})$$

4. Wave functions

The calculation of the wave function inside the scattering region proceeds in two steps. First, the wave functions in the leads, $|\psi_\alpha^i\rangle + |\psi_\alpha^r\rangle$ and $|\psi_\alpha^s\rangle$, Eqs. (B17), are determined from the transmission and reflection amplitudes [(B22) and (B23)]. The second step is recursive and requires the Green's functions in the scattering region. It starts from Eq. (B7) to obtain ψ_M , the wave function at the slice M next to the right lead, Fig. 7(c). Eq. (B7) can be rewritten in a general form,

$$\psi_i = \mathcal{G}_{i,1} U_{1,0} \psi_0 + \mathcal{G}_{i,i} U_{i,i+1} \psi_{i+1}, \quad (\text{B25})$$

and then applied again but for the slice $i = M-1$. By this way the recursion continues backward until the slice $i = 1$. Alternatively, one can start from Eq. (B6) and recurse forward to obtain the wave functions inside the scattering region.

5. Validity checks

The validity of the above method and its numerical implementation has been checked on several tests. The sum rule (B24), and thus unitarity of the scattering matrix and current conservation [24], is fulfilled with an accuracy greater than 10^{-2} . At $B = 0$ T, the conductance through a single constriction as presented in Ref. [46] was reproduced identically. Similarly, the wave functions and dispersion relation for ideal GNRs, both in armchair and zigzag orientations, were obtained in the quantitative agreement with the previous results [35,47,48]. At finite B , magnetic depopulation [24,27]

of electron quantization subbands was calculated in agreement with Refs. [10,21,49]. The dispersion relations shown in Fig. 6 are qualitatively similar to the ones presented in Refs. [15,26]. Landau levels, which can be traced in GNR bulk in Fig. 6,

agree reasonably well with the analytical result of the Dirac equation for 2D graphene [26], keeping also in mind that the energy levels in GNR is a result of both magnetic field and finite-size confinement.

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